

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicants: Leonard J. Olmer, *et al.*

Serial No.: 10/675,575

Filed: September 30, 2003

Title: IN-SITU REMOVAL OF SURFACE IMPURITIES PRIOR TO
ARSENIC-DOPED POLYSILICON DEPOSITION IN THE
FABRICATION OF A HETEROJUNCTION BIPOLAR
TRANSISTOR

Grp./A.U.: 1792

Examiner: Jason Mark Heckert

Confirmation No.: 9967

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

I hereby certify that this correspondence is being electronically filed
with United States Patent and trademark Office on:
December 15, 2008 (Date)

Elizabeth Schumacher
(Printed or typed name of person signing the certificate)

/Elizabeth Schumacher/
(Signature of the person signing the certificate)

Sir:

AMENDMENT UNDER 37 C.F.R. § 1.111

In response to the Examiner's Action mailed September 16, 2008, please amend the above-
identified application as follows: